Complementary Silicon Plastic Power Transistors

- ... designed for use in general-purpose amplifier and switching applications.
- DC Current Gain Specified to 10 Amperes
- High Current Gain Bandwidth Product f_T = 2.0 MHz (Min) @ I_C = 500 mAdc

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage	VCEO	60	Vdc	
Collector-Base Voltage	V _{CB}	70	Vdc	
Emitter–Base Voltage	VEB	5.0	Vdc	
Collector Current	IC	10	Adc	
Base Current	IB	6.0	Adc	
Total Power Dissipation @ T _C = 25°C Derate above 25°C MJE3055T, MJE2955T	P _D †	75 0.6	Watts W/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θЈС	1.67	°C/W

[†]Safe Area Curves are indicated by Figure 1. Both limits are applicable and must be observed.

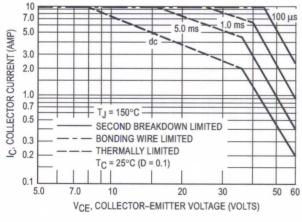
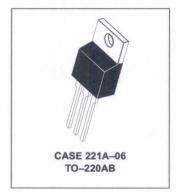


Figure 1. Active-Region Safe Operating Area

MJE2955T* NPN MJE3055T*

*Motorola Preferred Device

10 AMPERE
COMPLEMENTARY
SILICON
POWER TRANSISTORS
60 VOLTS
75 WATTS



There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 1 is based on $T_{J(pk)}$ = 150°C. T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150$ °C. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown. (See AN415A)

Preferred devices are Motorola recommended choices for future use and best overall value.

MJE2955T MJE3055T

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (1) (I _C = 200 mAdc, I _B = 0)	V _{CEO(sus)}	60	_	Vdc
Collector Cutoff Current (V _{CE} = 30 Vdc, I _B = 0)	ICEO	_	700	μAdc
Collector Cutoff Current (V _{CE} = 70 Vdc, V _{EB(off)} = 1.5 Vdc) (V _{CE} = 70 Vdc, V _{EB(off)} = 1.5 Vdc, T _C = 150°C)	ICEX	_	1.0 5.0	mAdc
Collector Cutoff Current $(V_{CB} = 70 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 70 \text{ Vdc}, I_E = 0, T_C = 150^{\circ}\text{C})$	ICBO	_	1.0 10	mAdc
Emitter Cutoff Current (V _{BE} = 5.0 Vdc, I _C = 0)	I _{EBO}	_	5.0	mAdc
ON CHARACTERISTICS				
DC Current Gain (1) (I _C = 4.0 Adc, V _{CE} = 4.0 Vdc) (I _C = 10 Adc, V _{CE} = 4.0 Vdc)	hFE	20 5.0	100	_
Collector–Emitter Saturation Voltage (1) (I _C = 4.0 Adc, I _B = 0.4 Adc) (I _C = 10 Adc, I _B = 3.3 Adc)	VCE(sat)	_	1.1 8.0	Vdc
Base–Emitter On Voltage (1) (I _C = 4.0 Adc, V _{CE} = 4.0 Vdc)	V _{BE(on)}	_	1.8	Vdc
DYNAMIC CHARACTERISTICS	,			
Current-Gain-Bandwidth Product (IC = 500 mAdc, VCE = 10 Vdc, f = 500 kHz)	fT	2.0	_	MHz

⁽¹⁾ Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 20%.

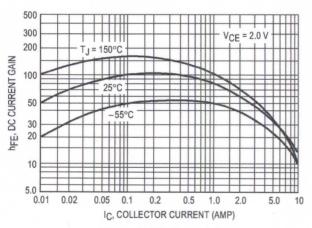


Figure 2. DC Current Gain

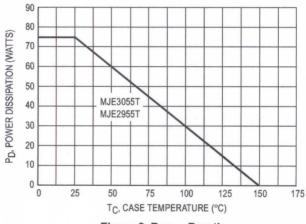
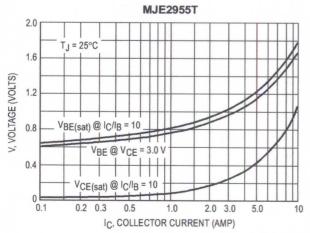


Figure 3. Power Derating



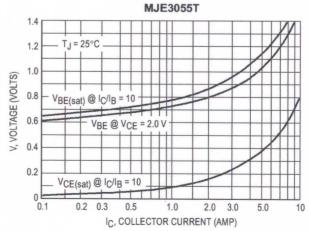
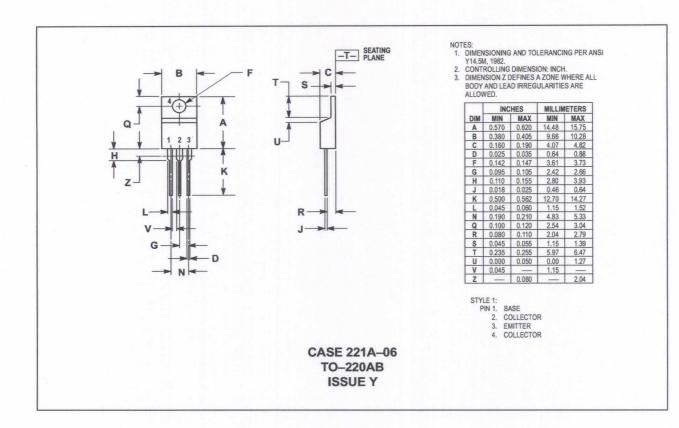


Figure 4. "On" Voltages

PACKAGE DIMENSIONS



MJE2955T MJE3055T

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How to reach us: USA/EUROPE: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447

MFAX: RMFAX0@email.sps.mot.com – TOUCHTONE (602) 244–6609 INTERNET: http://Design-NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, Toshikatsu Otsuki, 6F Seibu-Butsuryu-Center, 3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-3521-8315

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298



